

neutral edge-sharing octahedral nickel dimers **1** and **2**. Complexes of type **1**, with the Sal chelate plane essentially orthogonal to the Ni₂O₂ bridging plane, are ferromagnets, while type **2** complexes, with the Sal chelate plane nearly coplanar with the Ni₂O₂ bridge, are more strongly antiferromagnetic ($J = -9.2 \text{ cm}^{-1}$ for R = *i*-Pr, S' = dimethylformamide) than the [Ni₂(PhSal)₄CH₃COO]⁻ ion. Like the type **2** complexes, the acetate bridged dimeric ion has the Sal chelate plane roughly coplanar with the Ni₂O₂ bridging unit, which, however, is itself nonplanar. The Ni-O-Ni superexchange overlap is poorer in [Ni₂(PhSal)₄CH₃COO]⁻, leading

to weaker interaction, though this is mediated somewhat by the availability of the additional exchange path through the carboxylate ligand.

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Crystal Structure of a New Cesium Manganese Vanadium Oxide, Cs₃Mn₃V₄O₁₆

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Single crystals of Cs₃Mn₃V₄O₁₆ have been grown by molten salt electrolysis. They are triclinic, space group $P\bar{1}$, with the cell parameters $a = 5.1947(5) \text{ \AA}$, $b = 7.5017(7) \text{ \AA}$, $c = 11.4367(14) \text{ \AA}$, $\alpha = 77.70(1)^\circ$, $\beta = 89.72(1)^\circ$, $\gamma = 82.62(1)^\circ$, and $Z = 1$. The crystal structure was determined from single-crystal diffractometer data and refined to $R_F = 0.052$ for 3167 reflections observed with Mo K α radiation. The structure contains (CsMn₃V₄O₁₆)_n layers parallel to the *ab* plane and two Cs atoms per cell between them. In the layers, edge-sharing MnO₆ octahedra form flat ribbons of formula (Mn₃O₁₀)_n extending along *a*, which are bonded together in the *b* direction by two V₂O₇ double tetrahedra per cell, giving a two-dimensional framework with one large cavity per cell occupied by a Cs atom.

Introduction

During a study of the crystal growth of α -MnO₂ by electrolytic oxidation of Mn(II) dissolved in alkali vanadate melts, very different results were obtained according to the nature of the alkali metal.¹ Whereas potassium and rubidium were readily incorporated into the α -MnO₂ phase with a hollandite-type structure, electrolysis from a cesium vanadate melt yielded a new quaternary compound of formula Cs₃Mn₃V₄O₁₆. We present here the determination of its structure.

Experimental Section

Cs₃Mn₃V₄O₁₆ was formed by electrolysis in a melt of initial molar composition Cs₂CO₃ 36.4%, V₂O₅ 54.6%, and MnCO₃ 9.0% at 420 °C. The crystal growth process is described in detail in ref 1. The anodic deposit contained dark brown needles of a Cs-Mn-V-O compound up to 1 mm long. Preliminary examination using precession photographs indicated that they were single crystals of a new triclinic phase. Qualitative chemical analysis was performed with use of a scanning electron microscope equipped with an X-ray energy spectrometer.

X-ray Diffraction Data. The diffraction intensities of a 0.02 × 0.03 × 0.4 mm crystal were measured at 24 °C. Graphite-monochromatized Mo K α radiation generated at 50 kV and 10 mA was used in a $\theta/2\theta$ scan with line-profile analysis.² A total of 5369 unique measurements were made up to $2\theta = 80^\circ$, of which 3167 had $I_{\text{net}} > 3\sigma(I_{\text{net}})$ and were considered to be observed. No absorption correction was performed. The cell parameters were obtained by least-squares refinement of the setting angles of 30 reflections with $2\theta > 50^\circ$, using $\lambda(\text{Mo K}\alpha) = 0.7107 \text{ \AA}$. At 24 °C, they are as follows: $a = 5.1947(5) \text{ \AA}$, $b = 7.5017(7) \text{ \AA}$, $c = 11.4367(14) \text{ \AA}$, $\alpha = 77.70(1)^\circ$, $\beta = 89.72(1)^\circ$, $\gamma = 82.62(1)^\circ$. The cell volume is 431.72 Å³, and the calculated density is 3.936 g cm⁻³. The periods along *a*, *b*, and *c* were checked by oscillation patterns. The elongation of the needlelike crystals was parallel to the *a* axis.

Solution and Refinement of the Structure. The structure was solved by application of MULTAN³ to the 200 largest *E* values. The intensity

statistics indicated the presence of a center of symmetry, and we considered the space group to be $P\bar{1}$. One manganese and two cesium atoms were found on the *E* map. Two cycles of structure factor calculations followed by Fourier maps revealed all the atomic positions in the structure. All atomic positions were refined with anisotropic thermal motion by full-matrix least squares. An extinction correction was included.⁴ The scattering factors for the zerovalent atoms were taken from ref 5.

All the calculations were performed with use of the NRCC PDP8-E system of programs.⁶ The final residuals were $R_F = 0.052$ and $wR_F = 0.046$. The atomic positional and thermal parameters are listed in Table I. The bond distances and angles are listed in Tables II and III, respectively. The most intense lines of the powder pattern are given in Table IV. The observed powder pattern as well as the measured density were not obtained due to insufficient amounts of material.

Results and Discussion

Description of the Structure. Figures 1 and 2 show projections of the structure along *a* and *b*, respectively. The structure is based on octahedrally oxygen-coordinated manganese and tetrahedrally oxygen-coordinated vanadium atoms. It contains layers approximately 9 Å thick of composition (CsMn₃V₄O₁₆)_n parallel to the (001) plane. The layers are bonded in the *c* direction by two cesium atoms per cell (Cs_B in Table II). The layers are made of flat ribbons of formula (Mn₃O₁₀)_n bridged by V₂O₇ double tetrahedra, leaving large

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Table I. Atomic Parameters x , y , z , B_{iso} , and U Values $\times 100^a$

	x	y	z	$B_{\text{iso}}, ^b \text{Å}^2$
Cs _A	0	0	0	1.53 (4)
Cs _B	0.11310 (13)	0.26057 (9)	0.48568 (6)	1.82 (3)
Mn _A	1/2	1/2	0	0.55 (6)
Mn _B	0.01090 (22)	0.44142 (16)	0.13212 (11)	0.62 (5)
V _A	0.5266 (3)	0.13349 (19)	0.23364 (13)	0.70 (5)
V _B	0.4748 (3)	0.32817 (18)	0.76158 (12)	0.73 (5)
O _A	0.8074 (10)	0.6139 (7)	0.0076 (5)	0.68 (22)
O _B	0.3898 (12)	0.6394 (9)	0.3667 (6)	1.9 (3)
O _C	0.6522 (11)	0.1050 (8)	0.3676 (5)	1.3 (3)
O _D	0.3386 (11)	0.6038 (7)	0.1322 (5)	1.1 (3)
O _E	0.6962 (10)	0.2730 (7)	0.1288 (5)	0.85 (24)
O _F	0.2071 (11)	0.2371 (8)	0.2354 (5)	1.1 (3)
O _G	0.1698 (11)	0.4529 (8)	0.7422 (5)	1.2 (3)
O _H	0.4535 (12)	0.0841 (8)	0.8117 (6)	1.7 (3)

	$U_{11} (U, \text{Å}^2)$	U_{22}	U_{33}	U_{12}	U_{13}	U_{23}
Cs _A	1.85 (4)	1.38 (3)	2.97 (4)	-0.22 (3)	0.85 (3)	-0.84 (3)
Cs _B	2.67 (3)	2.21 (3)	2.22 (3)	0.142 (23)	0.101 (23)	-0.536 (22)
Mn _A	0.43 (7)	0.75 (7)	1.02 (7)	-0.12 (5)	0.10 (5)	-0.18 (6)
Mn _B	0.59 (5)	0.78 (5)	1.09 (5)	-0.08 (4)	0.12 (4)	-0.14 (4)
V _A	0.69 (6)	0.80 (5)	1.28 (6)	-0.11 (4)	0.05 (5)	-0.15 (4)
V _B	0.82 (6)	0.84 (5)	1.34 (6)	-0.22 (4)	0.14 (5)	-0.40 (5)
O _A	1.01 (25)	0.43 (22)	1.2 (3)	-0.03 (19)	0.05 (20)	-0.09 (19)
O _B	2.1 (3)	3.4 (4)	2.5 (4)	-0.6 (3)	0.7 (3)	-1.2 (3)
O _C	1.2 (3)	1.7 (3)	2.1 (3)	-0.03 (23)	-0.05 (24)	-0.04 (24)
O _D	1.3 (3)	1.3 (3)	1.6 (3)	-0.09 (22)	0.00 (22)	-0.46 (22)
O _E	0.81 (24)	1.1 (3)	1.5 (3)	-0.30 (20)	0.41 (21)	-0.17 (21)
O _F	1.1 (3)	1.5 (3)	1.6 (3)	0.05 (22)	0.03 (22)	0.42 (22)
O _G	1.5 (3)	1.4 (3)	1.7 (3)	-0.25 (23)	-0.08 (23)	-0.37 (23)
O _H	2.4 (3)	1.0 (3)	3.8 (4)	-0.34 (24)	0.7 (3)	-1.3 (3)

^a Esd's refer to the last digit printed. ^b B_{iso} is the arithmetic mean of the principal axes of the thermal ellipsoid.

Table II. Interatomic Distances (Å) in $\text{Cs}_3\text{Mn}_3\text{V}_4\text{O}_{16}$ ^a

	O _A	O _B	O _C	O _D	O _E	O _F	O _G	O _H
Mn _A	1.916 (5) ^{II}			1.979 (5) ^{II}	2.147 (5) ^{II}			
Mn _B	1.923 (5)			2.217 (6)	2.196 (5)	1.903 (5)	1.964 (6)	
	1.945 (5)							
V _A			1.629 (6)		1.732 (5)	1.742 (5)		1.806 (6)
V _B		1.608 (6)		1.754 (6)			1.723 (6)	1.816 (6)
Cs _A	3.168 (5) ^{II}			3.314 (5) ^{II}	3.048 (5) ^{II}	3.759 (6) ^{II}		3.215 (6) ^{II}
								3.481 (7) ^{II}
Cs _B		3.372 (7)	3.290 (6)			2.940 (6)	3.563 (6)	
		3.341 (7)	3.215 (6)				3.226 (6)	
		3.199 (6)	3.004 (6)					

^a Numbers in parentheses are estimated standard deviations applying to the last digit. Superscript Roman numerals indicate the bond multiplicity at the cation.

cavities inside the layers, which are occupied by the Cs_A atoms (see Figure 1).

The shape of the $(\text{Mn}_3\text{O}_{10})_n$ ribbons is shown in Figure 3. It is based on units of three octahedra containing one Mn_A and two Mn_B atoms. The Mn_AO₆ octahedra share one edge with each of the four adjacent Mn_BO₆ octahedra. The latter share a total of three edges (two with Mn_AO₆, one with Mn_BO₆ octahedra). The ribbons, extending along a , are approximately parallel to the (031) plane. The (001) plane is a pseudomirror for the $(\text{CsMn}_3\text{V}_4\text{O}_{16})_n$ layer, but the distribution of the cesium atoms and the stacking of the layers destroy this approximate symmetry.

Discussion. The manganese octahedra in this structure are very distorted. Mn—O distances vary from 1.90 to 2.21 Å and O—Mn—O angles from 80 to 98° (see Tables II and III). Fairly short Mn—O bond lengths are found with the O_A atom, which is shared by three manganese octahedra and one cesium atom. It is the only oxygen atom that has no vanadium neighbor. In the equally distorted V₂O₇ double tetrahedra, the longest V—O distance (1.81 Å) is found with the bridging O_H atom, whereas the O_B and O_C atoms, which are bonded to one vanadium and three cesium neighbors, have very short V—O bond

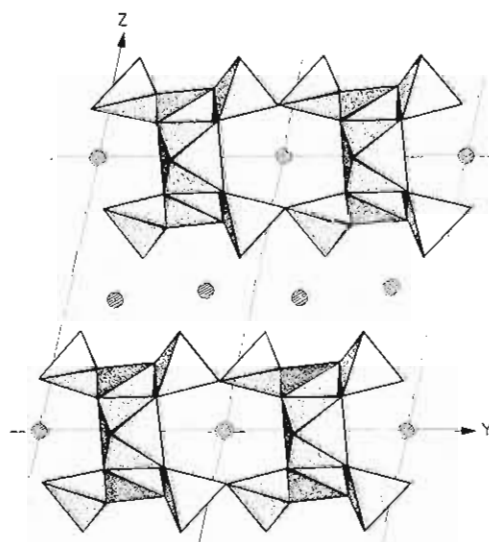


Figure 1. Orthogonal projection of the structure along a . The Mn and V atoms are respectively octahedrally and tetrahedrally coordinated. The cesium atoms are shown as small spheres.

Table III. Bond Angles (Deg) in $Cs_3Mn_3V_4O_{16}$ ^a

Mn Octahedra			
Mn_AO_6			
$O_A-Mn_A-O_A'$	180.0	$O_D-Mn_A-O_D'$	180.0
$O_A-Mn_A-O_D$	92.6 (2)	$O_D-Mn_A-O_E$	89.6 (2)
$O_A-Mn_A-O_D'$	87.4 (2)	$O_D-Mn_A-O_E'$	90.4 (2)
$O_A-Mn_A-O_E$	85.7 (2)	$O_E-Mn_A-O_E'$	180.0
$O_A-Mn_A-O_E'$	94.3 (2)		
Mn_BO_6			
$O_A-Mn_B-O_A$	80.1 (3)	$O_A'-Mn_B-O_H$	168.9 (3)
$O_A-Mn_B-O_D$	96.6 (3)	$O_D-Mn_B-O_E$	177.8 (3)
$O_A-Mn_B-O_E$	84.1 (3)	$O_D-Mn_B-O_F$	89.9 (3)
$O_A-Mn_B-O_F$	168.6 (3)	$O_D-Mn_B-O_G$	92.9 (3)
$O_A-Mn_B-O_G$	92.1 (3)	$O_E-Mn_B-O_F$	89.1 (3)
$O_A'-Mn_B-O_D$	80.3 (3)	$O_E-Mn_B-O_G$	89.2 (3)
$O_A'-Mn_B-O_F$	97.8 (3)	$O_F-Mn_B-O_G$	97.0 (3)
$O_A'-Mn_B-O_G$	91.8 (3)		
V Tetrahedra			
V_AO_4			
$O_C-V_A-O_E$	111.2 (3)	$O_E-V_A-O_F$	109.2 (3)
$O_C-V_A-O_F$	107.8 (3)	$O_E-V_A-O_H$	106.1 (3)
$O_C-V_A-O_H$	110.5 (3)	$O_F-V_A-O_H$	112.1 (3)
V_BO_4			
$O_B-V_B-O_D$	110.7 (3)	$O_D-V_B-O_G$	111.5 (3)
$O_B-V_B-O_G$	107.2 (3)	$O_D-V_B-O_H$	108.1 (3)
$O_B-V_B-O_H$	108.5 (3)	$O_G-V_B-O_H$	110.8 (3)

^a Numbers in parentheses are estimated standard deviations applying to the last digit.

Table IV. Abbreviated Powder Pattern of $Cs_3Mn_3V_4O_{16}$ Calculated from the Single-Crystal Structure Determination^a

<i>d</i>	<i>I</i>	<i>hkl</i>	<i>d</i>	<i>I</i>	<i>hkl</i>
11.15	31	001	3.195	74	121
5.583	20	002	3.038	50	113 ^b
4.333	20	111	2.9323	56	023
4.008	43	111	2.8378	44	121
3.828	71	102	2.7912	30	004
3.742	82	102 ^b	2.7186	22	113
3.693	26	021	2.5745	22	200
3.458	36	112	2.4429	43	114 ^b
3.255	100	021			

^a Lines with *I* > 20 only; the complete powder pattern is available as supplementary material. ^b More than one reflection contributes to this line; the indices given are those of the most intense contributor.

lengths (~1.61 Å). The two crystallographically distinct cesium sites have high coordinations. The Cs_A atoms, which are imbedded in the layers, have twelve oxygen neighbors at

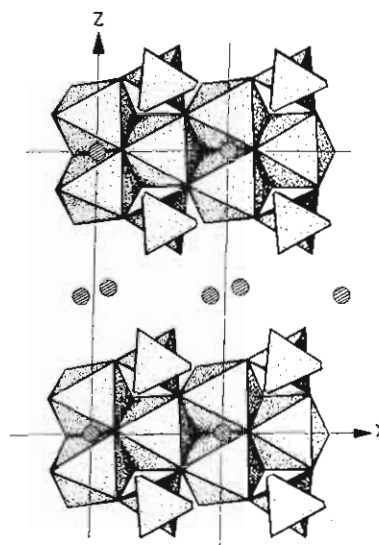


Figure 2. Orthogonal projection of the structure along *b*. The V_2O_7 double tetrahedra link ribbons that correspond through translations along *b* (see Figure 1). Accordingly, the corners of the tetrahedra that attach to the next ribbon have been shown truncated.

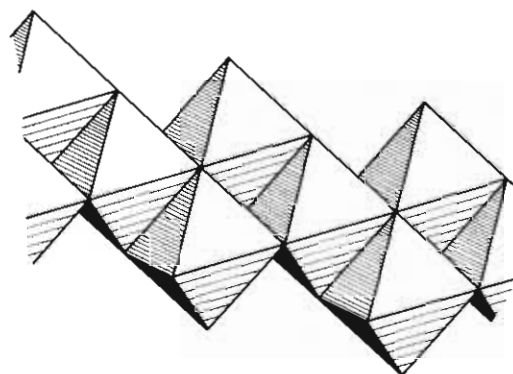


Figure 3. Perspective view of the $(Mn_3O_{10})_n$ ribbon.

distances ranging from 3.05 to 3.76 Å whereas the interlayer Cs_B atoms are in ninefold coordination with slightly shorter $Cs-O$ distances (2.94–3.56 Å).

The structural characteristics of manganese and vanadium in $Cs_3Mn_3V_4O_{16}$ and in some typical oxidic compounds of Mn(+3 or +4) and V(+4 or +5) are compared in Table V. The manganese ions are always found with octahedral coordination (for example, Mn^{3+} has one of the highest octahedral

Table V. Structural Characteristics of Some Typical Mn^{3+} , Mn^{4+} , V^{4+} , and V^{5+} Oxidic Compounds^{7,8}

ion	compd	struct type	coord no.	av bond length, Å
Mn^{3+}	Mn_2O_3	C-rare earth	6	2.00
	$M^I MnO_2$	distorted β - $NaFeO_2$	6	2.08 (M = Li)
	$M^{II} Mn_2O_4$	distorted spinel	6	2.00 (M = Mn)
	$M^{III} MnO_3$	distorted perovskite	6	1.97 (M = La)
Mn^{4+}	β - MnO_2	rutile	6	1.89
	$M^{II} MnO_3$	perovskite or ilmenite	6	1.86 (M = Ca)
	$M^{II} Mn_3O_8$	(ribbons, Mn_3O_{10}) ¹⁰	6	1.89 (M = Co)
Mn in $Cs_3Mn_3V_4O_{16}$		(ribbons, Mn_3O_{10})	6	2.01
V^{4+}	VO_2	distorted rutile	6	1.93
	$M^{II} V_2O_4$	spinel	6	1.88 (M = Mg)
	$M^{II} VO_3$	perovskite or ilmenite	6	1.88 (M = Ca)
V^{5+}	V_2O_5	(layer structure)	5	1.83
	$M^I VO_3$	(chains, $(VO_3)_n$)	4, 5	1.72 (M = Na)
	$M^{II} V_2O_7$	(double tetrahedra, V_2O_7)	4	1.71 (M = Mg)
	$M^{III} VO_4$	scheelite, zircon	4	1.71 (M = La)
V in $Cs_3Mn_3V_4O_{16}$		(double tetrahedra, V_2O_7)	4	1.73

site preference energy in spinels⁹). Mn^{3+} and Mn^{4+} compounds differ by the occurrence of strong Jahn-Teller distortions in the former, due to the d^4 electronic configuration of Mn^{3+} . Whereas the six Mn^{4+} -O bond lengths are nearly equal in β - MnO_2 (1.88-1.91 Å), the Mn^{3+} ions in Mn_2O_3 have four oxygen neighbors at ~ 1.96 Å and two oxygen neighbors at 2.06 or 2.25 Å.⁷ A very similar distortion occurs in $Cs_3Mn_3V_4O_{16}$, with four "short" Mn-O distances (1.90-1.98 Å) and two "long" Mn-O distances at 2.15-2.22 Å (see Table II). The structural features of V^{4+} and V^{5+} are very different from each other. V^{4+} is usually octahedrally coordinated, whereas V^{5+} is found mostly with coordination numbers 4 or 5. The double tetrahedron (V_2O_7) occurs in the structure of several mixed oxides with the formula $M_2^{II}V_2O_7$.⁸ Thus it can be seen from Table V that $Cs_3Mn_3V_4O_{16}$ exhibits structural characteristics of Mn^{3+} (average bond length, Jahn-Teller distortion) and of V^{5+} (bond length, coordination). The charge distribution is most probably $(Cs^+)_3(Mn^{3+})_3(V^{5+})_4(O^{2-})_{16}$, as expected from the crystal growth process, which was based on oxidation in a medium containing Mn^{2+} and V^{5+} ions.

The structure of $Cs_3Mn_3V_4O_{16}$, characterized by ribbons of $(Mn_3O_{10})_n$ bridged by V_2O_7 double tetrahedra, is new. Apart from oxide solid solutions (Mn, V) O_2 , no mixed oxides containing both Mn(3+ or 4+) and V(4+ or 5+) are known. Most manganese complex oxides belong to structural types derived from close-packed arrays of oxygen anions. Ribbons of edge-sharing (MnO_6) octahedra have been found in the Mn^{4+} compounds $Co_2Mn_3O_8$ and $Cu_2Mn_3O_8$,¹⁰ but with a

different spatial arrangement leading to a ribbon composition $(Mn_3O_8)_n$. A ribbon $(A_3O_{10})_n$ with the same architecture as in $Cs_3Mn_3V_4O_{16}$ occurs in lindgrenite, a copper(II) hydroxomolybdate of formula $2CuMoO_4 \cdot Cu(OH)_2$, with ribbon composition $[Cu_3O_8(OH)_2]_n$.¹¹

Other Properties. The magnetization in $Cs_3Mn_3V_4O_{16}$ was measured in the range 4.2-60 K with use of a vibrating-sample magnetometer in a field of 20 kOe. There was no evidence of magnetic ordering, and the sample appeared to be paramagnetic down to 4.2 K. The Curie constant could not be determined due to the very small amounts of substance available (~ 0.3 mg).

Finally, the Mn-Mn distances between adjacent Mn_A and Mn_B atoms in the ribbons is 2.98 Å. Comparison of this value with the critical distance R_c defined by Goodenough¹² as a criterion for localized vs. collective electron transport behavior indicates that no collective (metallic) electronic properties should be expected in this material ($R_c[Mn^{3+}] = 2.72$ Å).

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Registry No. $Cs_3Mn_3V_4O_{16}$, 80105-64-2.

Supplementary Material Available: A listing of calculated and observed structure factors and complete listing (100 lines for $2\theta(Cu K\alpha)$ up to 58°) of the calculated powder pattern (36 pages). Ordering information is given on any current masthead page.

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Structure of

Oxobis(dimethyldithiocarbamato)(dibenzoyldiazene)molybdenum-1,2-Dichloroethane, $MoO(PhCONNCOPh)(S_2CNMe_2)_2 \cdot C_2H_4Cl_2$

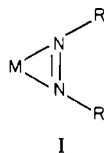
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The X-ray crystal and molecular structure of oxobis(dimethyldithiocarbamato)(dibenzoyldiazene)molybdenum-1,2-dichloroethane, $MoO(C_3H_6NS)_2(C_{14}H_{10}N_2O_2) \cdot C_2H_4Cl_2$, was determined from intensity data collected with use of counter methods. The compound crystallizes in the space group $P2_1/c$ with the parameters $a = 10.035$ (2) Å, $b = 16.360$ (8) Å, $c = 18.649$ (6) Å, $\beta = 104.00$ (2)°, $V = 2970.7$ (18) Å³, and $Z = 4$; $d_{calcd} = 1.54$ g/mL, $d_{obsd} = 1.55$ g/mL, and conventional R value = 0.058. The crystal structure contains discrete monomers. The approximate stereochemistry about the molybdenum atom is pentagonal bipyramidal. The four sulfur atoms of the dithiocarbamate ligands and N1 of the benzoyldiazene ligand occupy the equatorial positions. The axial sites are occupied by the terminal oxo group and O1 of the diazene ligand. The bidentate diazene ligand coordinates to Mo through N1 and O1 to form a five-membered chelate ring. The angle between the trans oxygen atoms is 166.0° , N1-N2 = 1.418 (14) Å, C1-N2 = 1.295 (10) Å, Mo-O = 1.685 (10) Å, and (Mo-S)_{av} = 2.525 (14) Å. The dichloroethane of crystallization is disordered.

Introduction

The stereochemistry of transition-metal complexes of diazenes is of interest because several postulated mechanisms for the reduction of coordinated dinitrogen to ammonia involve η^2 -diazenes (I) as intermediates or transition states.²⁻⁴ There



are relatively few well-documented η^2 complexes of diazenes and other reduced nitrogen ligands. Some examples include the azobenzene⁵ and diazofluorene⁶ complexes of nickel(0), the η^2 -hydrazine complex⁷ (η - C_5H_5)Mo(NO)I(N₂H₃Ph), and the η^2 -hydrazido(1-) complexes⁸ (η - C_5H_5)₂W(N₂H₂Ph)⁺ and

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